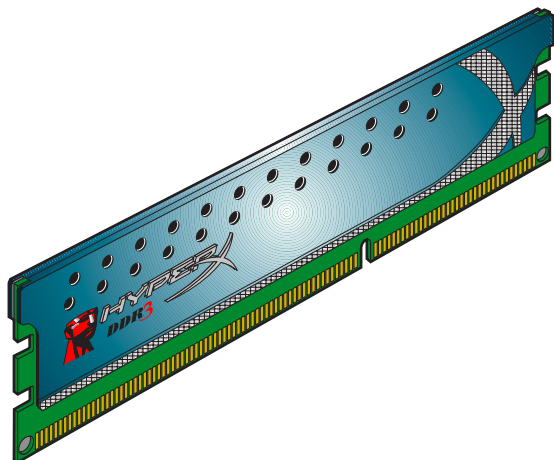


**KHX1866C9D3K3/12GX**

12GB (4GB 512M x 64-Bit x 3 pcs.)  
DDR3-1866 CL9 240-Pin DIMM Kit

**DESCRIPTION**

Kingston's KHX1866C9D3K3/12GX is a kit of three 512M x 64-bit (4GB) DDR3-1866 CL9 SDRAM (Synchronous DRAM) 2Rx8 memory modules, based on sixteen 256M x 8-bit DDR3 FBGA components per module. Each module kit supports **Intel® XMP** (Extreme Memory Profiles). Total kit capacity is 12GB. Each module kit has been tested to run at DDR3-1866 at a low latency timing of 9-11-9-27 at 1.65V. For additional supported timing parameters see the information below. The SPDs are programmed to JEDEC standard latency DDR3-1333 timing of 9-9-9 at 1.5V. Each 240-pin DIMM uses gold contact fingers and requires +1.5V. The JEDEC standard electrical and mechanical specifications are as follows:

**TIMING PARAMETERS:**

- JEDEC: DDR3-1333 CL9-9-9 @1.5V
- XMP Profile #1: DDR3-1866 CL9-11-9-27 @1.65V
- XMP Profile #2: DDR3-1600 CL9-9-9-27 @1.65V

**SPECIFICATIONS**

|  |                       |
|--|-----------------------|
| CL(IDD)  | 9 cycles              |
| Row Cycle Time (tRCmin)                          | 49.5ns (min.)         |
| Refresh to Active/Refresh Command Time (tRFCmin) | 160ns (min.)          |
| Row Active Time (tRASmin)                        | 36ns (min.)           |
| Power (Operating)                                | 1.410 W* (per module) |
| UL Rating  | 94 V - 0              |
| Operating Temperature                            | 0° C to 85° C         |
| Storage Temperature                              | -55° C to +100° C     |

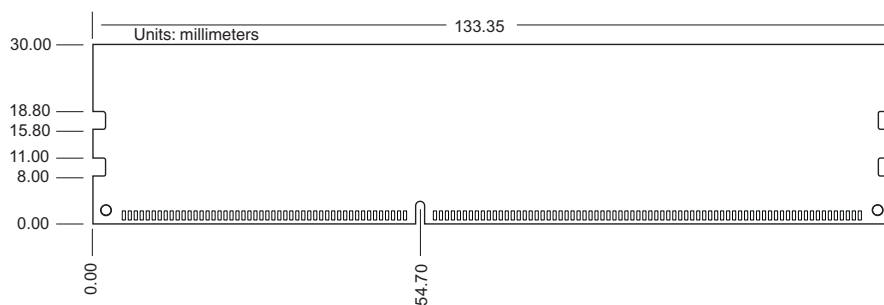
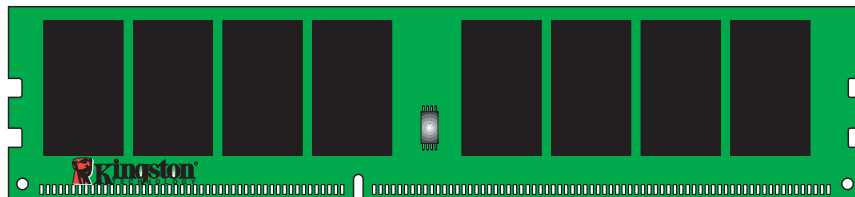
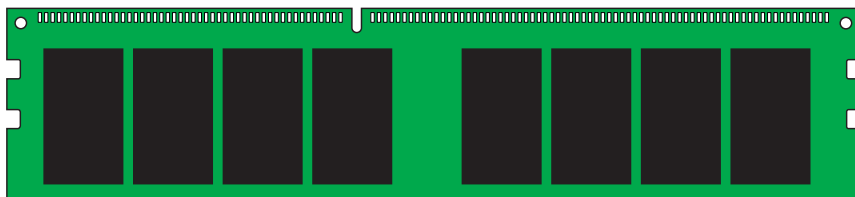
\*Power will vary depending on the SDRAM used.

**FEATURES**

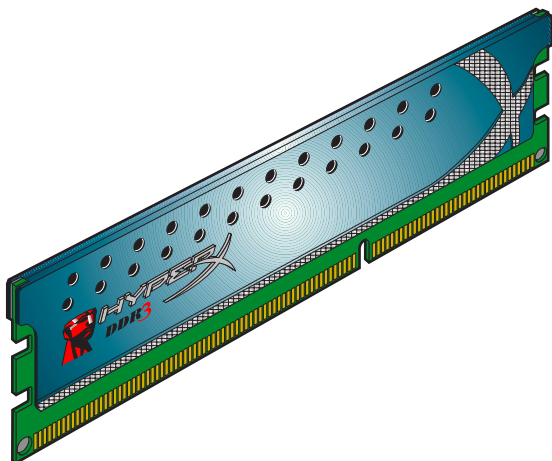
- JEDEC standard 1.5V (1.425V ~ 1.575V) Power Supply
- VDDQ = 1.5V (1.425V ~ 1.575V)
- 667MHz fCK for 1333Mb/sec/pin
- 8 independent internal bank
- Programmable CAS Latency: 9, 8, 7, 6
- Posted CAS
- Programmable Additive Latency: 0, CL - 2, or CL - 1 clock
- Programmable CAS Write Latency(CWL) = 7 (DDR3-1333)
- 8-bit pre-fetch
- Burst Length: 8 (Interleave without any limit, sequential with starting address "000" only), 4 with tCCD = 4 which does not allow seamless read or write [either on the fly using A12 or MRS]
- Bi-directional Differential Data Strobe
- Internal(self) calibration : Internal self calibration through ZQ pin (RZQ : 240 ohm ± 1%)
- On Die Termination using ODT pin
- Average Refresh Period 7.8us at lower than TCASE 85°C, 3.9us at 85°C < TCASE ≤ 95°C
- Asynchronous Reset
- PCB : Height 1.180" (30.00mm), double sided component

Continued >>

## MODULE DIMENSIONS



## MODULE WITH HEAT SPREADER



FOR MORE INFORMATION, GO TO [WWW.KINGSTON.COM](http://WWW.KINGSTON.COM)

All Kingston products are tested to meet our published specifications. Some motherboards or system configurations may not operate at the published HyperX memory speeds and timing settings. Kingston does not recommend that any user attempt to run their computers faster than the published speed. Overclocking or modifying your system timing may result in damage to computer components.